



650 V 55 mΩ SiC MOSFET

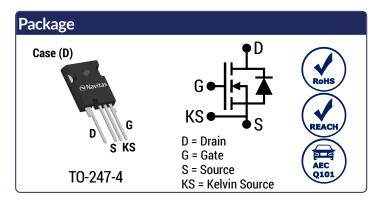
Silicon Carbide MOSFET

Trench-Assisted Planar Technology

 $\begin{array}{cccc} V_{DS} & = & 650 \text{ V} \\ R_{DS(ON)}(Typ.) = & 55 \text{ m}\Omega \\ I_{D} (T_{C} = 100^{\circ}\text{C}) & = & 30 \text{ A} \end{array}$

Features

- Gen3F (3rd Generation) Technology
- Most Stable R_{DS(ON)} over Temperature
- Low Coss, Crss and Balanced Ciss/Crss
- Lower Q_{GD} and Balanced R_{G(INT)}
- Electromagnetically Optimized Design
- Robust Body Diode with Low V_F and Low Q_{RR}
- 100% Avalanche (UIL) Tested
- AEC-Q101 Qualified



Advantages

- Superior Performance and Robustness
- Lowest Conduction Losses at all Temperatures
- Lesser Switching Spikes and Lower Losses
- Faster and More Efficient Switching
- Reduced Ringing
- Ease of Paralleling without Thermal Runaway
- Excellent Power Density and System Efficiency
- Enhanced System Reliability

Applications

- xEV DC-DC
- Server & Telecom Power Supply
- Solar / PV
- Energy Storage System
- Uninterruptible Power Supply
- Class D Amplifiers

Absolute Maximum Ratings (At T _C = 25°C Un	less Otherwise Sta	ated)			
Parameter	Symbol	Conditions	Values	Unit	Note
Drain-Source Voltage	$V_{\text{DS(max)}}$	V_{GS} = 0 V, I_D = 100 μA	650	V	
Gate-Source Voltage (Dynamic)	$V_{\text{GS(max)}}$		-10 / +22	V	
Cata Sauraa Valtaga (Statia)	$V_{GS(op)\text{-}ON}$	Recommended Operation	15 to 18	V	Note 1
Gate-Source Voltage (Static)	$V_{GS(op)\text{-}OFF}$	necommended operation	-5 to -3	V	Note i
		$T_C = 25^{\circ}C$, $V_{GS} = -5 / +18 V$	42		
Continuous Drain Current	I_D	$T_C = 100$ °C, $V_{GS} = -5 / +18 V$	30	Α	Fig. 16
		$T_C = 135^{\circ}C$, $V_{GS} = -5 / +18 V$	22		
Pulsed Drain Current	I _{D(pulse)}	$t_P \le 3\mu s$, $D \le 1\%$, $V_{GS} = 18~V$	75	Α	Note 2
Power Dissipation	P_D	$T_c = 25^{\circ}C$	140	W	Fig. 17
Non-Repetitive Avalanche Energy	Eas	$L = 36 \text{ mH}, I_{AV} = 3 \text{ A}$	162	mJ	
Operating Junction and Storage Temperature	T_{j} , T_{stg}		-55 to 175	°C	

Note 1: This product can support 0V turn-off gate drive voltage with optimized PCB layout and gate drive circuit configuration.

Note 2: Pulse Width tp Limited by T_{j(max)}



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Electrical Characteristics (At	T _C = 25°C Unlo	ess Otherwise Stated)					
Daramatar	Cumbal	Conditions		Values		Unit	Note
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	Note
Drain-Source Breakdown Voltage	V_{DSS}	$V_{GS} = 0 \text{ V, } I_D = 100 \mu\text{A}$	650			V	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 650 \text{ V}, V_{GS} = 0 \text{ V}$		1	50	μΑ	
Gate Source Leakage Current	lana	$V_{DS} = 0 \text{ V, } V_{GS} = 22 \text{ V}$			100	nA	
Gate Source Leakage Current	I _{GSS}	V_{DS} = 0 V, V_{GS} = -10 V			-100	IIA	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 7 \text{ mA}$	2.2	2.7	4.3	V	Note 3
Transconductance	Or.	$V_{DS} = 10 \text{ V, } I_D = 15 \text{ A}$		7.8		S	Fig. 5
Transconductance	G fs	$V_{DS} = 10 \text{ V, } I_D = 15 \text{ A, } T_j = 175 ^{\circ}\text{C}$		7.9			1 ig. 5
		$V_{GS} = 18 \text{ V, } I_D = 15 \text{ A}$		55	75		
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} = 18 V, I_D = 15 A, T_j = 175°C		78		mΩ	Fig. 5-9
Drain Source on State Hesistance	I IDS(ON)	$V_{GS} = 15 \text{ V, } I_D = 15 \text{ A}$		68		11122	1 lg. 5-9
		$V_{GS} = 15 \text{ V}, I_D = 15 \text{ A}, T_j = 175^{\circ}\text{C}$		83			
Input Capacitance	Ciss	_		1322			
Output Capacitance	Coss	_		90		pF	Fig. 12
Reverse Transfer Capacitance	C _{rss}	_		4.5			
Coss Stored Energy	E _{oss}	$ V_{DS} = 400 \text{ V, } V_{GS} = 0 \text{ V}$ -		8		μJ	Fig. 13
Coss Stored Charge	Q _{oss}	f = 500 KHz, V _{AC} = 25mV		57		nC	
Effective Output Capacitance (Energy Related)	$C_{o(\text{er})}$			100			Note 4
Effective Output Capacitance (Time Related)	C _{o(tr)}			142		pF	Note 4
Gate-Source Charge	Q_{gs}	$V_{DS} = 400 \text{ V}, V_{GS} = -5 / +18 \text{ V}$		11			
Gate-Drain Charge	Q_{gd}	I _D = 15 A		13		nC	Fig. 11
Total Gate Charge	Q_g	Per JEDEC JEP-192		45			
Internal Gate Resistance	$R_{G(int)}$	$V_{GS} = 18 \text{ V, } f = 1 \text{ MHz, } V_{AC} = 25 \text{ mV}$		1.8		Ω	
Turn-On Switching Energy (Body Diode)	E _{On}	$T_{\rm j}$ = 25°C, $V_{\rm GS}$ = -5/+18V, $R_{\rm G(ext)}$ = 6.8 Ω, L		55		1	Fin 04 07
Turn-Off Switching Energy (Body Diode)	E _{Off}	= 80.0 μH, I _D = 15 A, V _{DD} = 400 V		29		μJ	Fig. 24-27
Turn-On Delay Time	t _{d(on)}			24			
Rise Time	t _r	$V_{DD} = 400 \text{ V}, V_{GS} = -5/+18 \text{ V}$		8			Fi. 00
Turn-Off Delay Time	t _{d(off)}	$R_{G(ext)} = 6.8 \Omega$, L = 80.0 μH, $I_D = 15 A$ Timing relative to V_{DS} , Inductive load		15		ns	Fig. 26
Fall Time	t _f	— Tilling relative to VDS, illudutive load –		7			

Note 3: Tested after applying 30ms pulse at Vgs= +25V

Note 4: $C_{O(er)}$, a lumped capacitance that gives same stored energy as C_{OSS} while V_{DS} is rising from 0 to 400V. $C_{O(tr)}$, a lumped capacitance that gives same charging times as C_{OSS} while V_{DS} is rising from 0 to 400V.

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Reverse Diode Characterist	ics						
Parameter	Symbol	Conditions		Values		Unit	Note
Falanetei	Syllibol	Conditions	Min.	Тур.	Max.	Ullit	Note
Diode Forward Voltage	V_{SD}	V_{GS} = -5 V, I_{SD} = 7 A		4.4		V F	Fig. 18-19
blode Forward Voltage	VSD	V_{GS} = -5 V, I_{SD} = 7 A, T_j = 175°C		3.9		V	Fig. 10-19
Continuous Diode Forward Current	l _a	$V_{GS} = -5 \text{ V, } T_c = 25^{\circ}\text{C}$			23		
	ls	V_{GS} = -5 V, T_c = 100°C			13	Α	
Diode Pulse Current	I _{S(pulse)}	V _{GS} = -5 V		52		Α	Note 2
Reverse Recovery Time	t _{rr}	V 5VI 15AV 400V		5.9		ns	
Reverse Recovery Charge	Qrr	$V_{GS} = -5 \text{ V, } I_{SD} = 15 \text{ A, } V_{R} = 400 \text{ V}$ $dif/dt = 6000 \text{ A/}\mu\text{s, } T_{i} = 25^{\circ}\text{C}$		61		nC	
Peak Reverse Recovery Current	I _{rrm}	uii/ut = 0000 A/μs, 1] = 25 C		12		Α	
Reverse Recovery Time	t _{rr}	V 5VI 154 V 400V		7		ns	
Reverse Recovery Charge	Q _{rr}	$V_{GS} = -5 \text{ V, } I_{SD} = 15 \text{ A, } V_{R} = 400 \text{ V}$ $dif/dt = 6000 \text{ A/}\mu\text{s, } T_{i} = 175^{\circ}\text{C}$		116		nC	
Peak Reverse Recovery Current	I _{rrm}	uii/ut - 0000 A/μs, 1 _J - 175 C		17.5		Α	

Package Characteristics					
Parameter	Symbol	Conditions	Values	Unit	Note
Max Thermal Resistance, Junction - Case	R _{thJC-Max}	Maximum	1.07	°C/W	Fig. 14
Weight	W_{T}		6.2	g	
Moisture Sensitivity Level	MSL		N/A		
EMC Material Group			II		
Max Mounting Torque	T_M	Screws to Heatsink	1.1	Nm	

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Fig 1: Typical Output Characteristics ($T_j = 25$ °C)

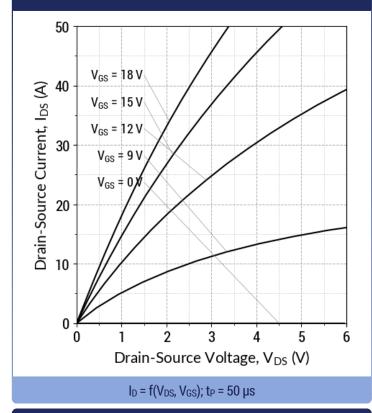
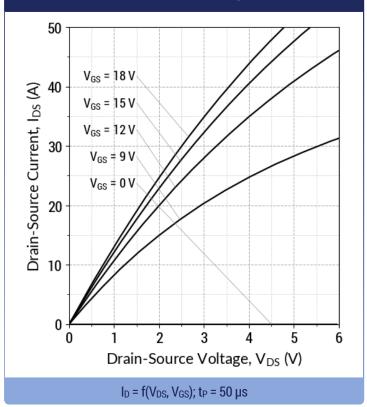


Fig 2: Typical Output Characteristics (T_j = 175°C)



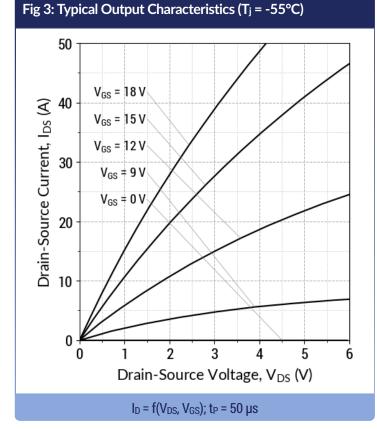
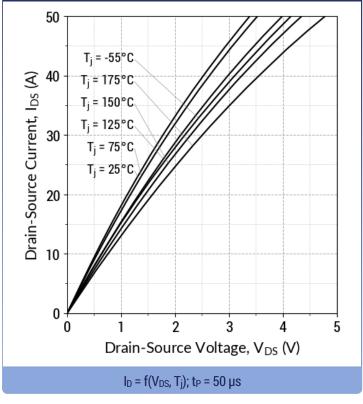
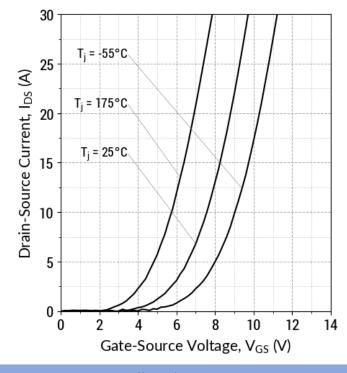


Fig 4: Typical Output Characteristics (V_{GS} = 18 V)



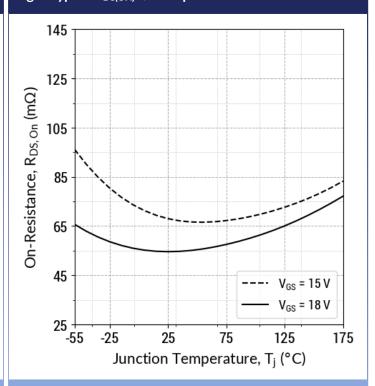
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Fig 5: Typical Transfer Characteristics (V_{DS} = 10 V)



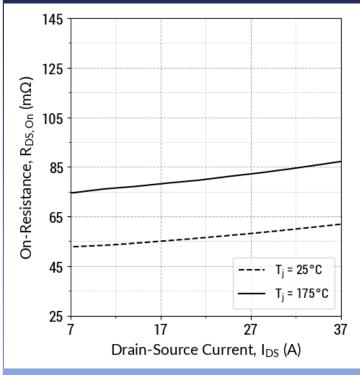
 $I_D = f(V_{GS}, T_j); t_P = 100 \mu s$

Fig 6: Typical R_{DS(ON)} v/s Temperature



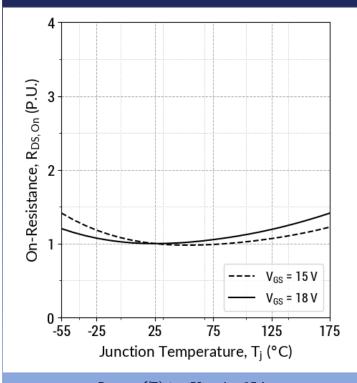
 $R_{DS(ON)} = f(T_j, V_{GS}); t_P = 50 \mu s; I_D = 15 A$

Fig 7: Typical RDS(ON) v/s Drain Current



 $R_{DS(ON)} = f(T_i, I_D); t_P = 50 \mu s; V_{GS} = 18 \text{ V}$

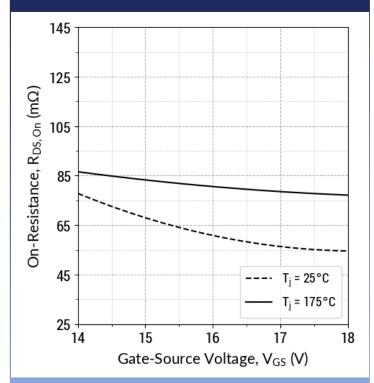
Fig 8: Typical Normalized RDS(ON) v/s Temperature



 $R_{DS(ON)} = f(T_j); t_P = 50 \mu s; I_D = 15 A$

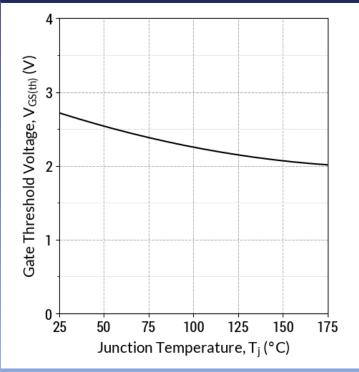
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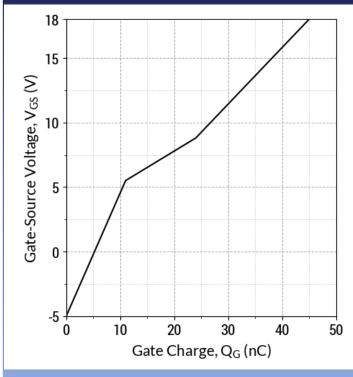
 $R_{DS(ON)} = f(T_i, V_{GS}); t_P = 50 \mu s; I_D = 15 A$

Fig 10: Typical Threshold Voltage Characteristics



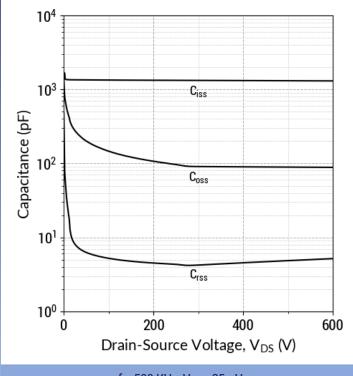
 $V_{GS(th)} = f(T_j)$; $V_{DS} = V_{GS}$; $I_D = 7 \text{ mA}$

Fig 11: Typical Gate Charge Characteristics



 $I_D = 15 \text{ A}$; $V_{DS} = 400 \text{ V}$; $T_c = 25^{\circ}\text{C}$

Fig 12: Typical Capacitance v/s Drain-Source Voltage



 $f = 500 \text{ KHz}; V_{AC} = 25 \text{mV}$

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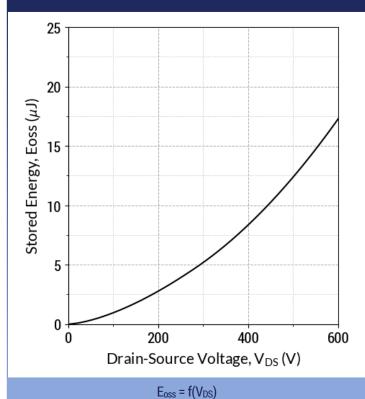


Fig 14: Max. Transient Thermal Impedance

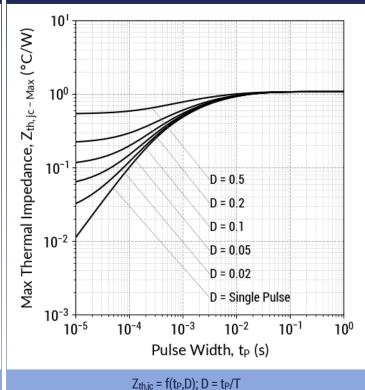


Fig 15: Safe Operating Area ($T_c = 25$ °C)

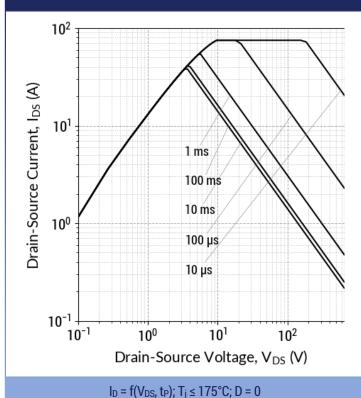
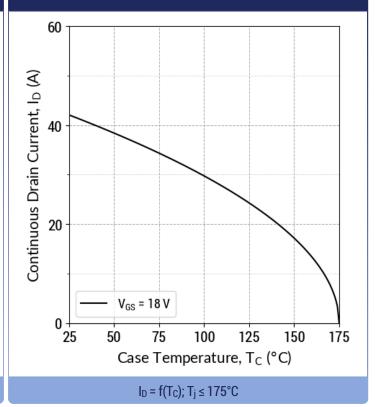
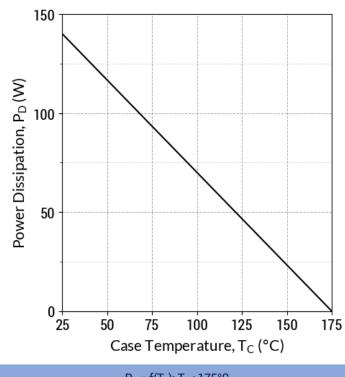


Fig 16: Current De-rating Curve



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 $P_D = f(T_C); T_j \le 175^{\circ}C$

Fig 18: Typical Body Diode Characteristics ($T_j = 25$ °C)

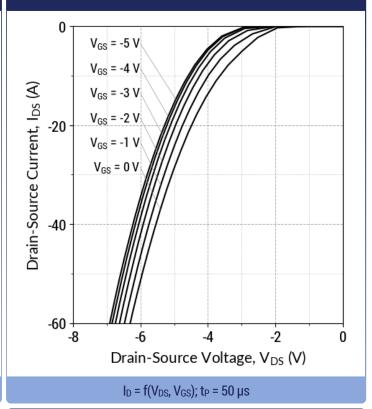


Fig 19: Typical Body Diode Characteristics ($T_j = 175$ °C)

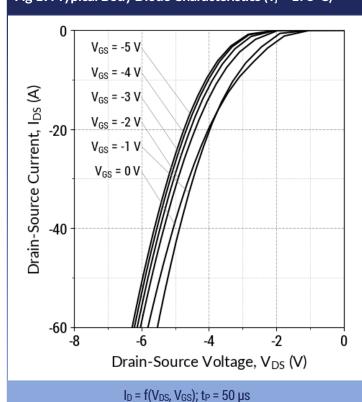
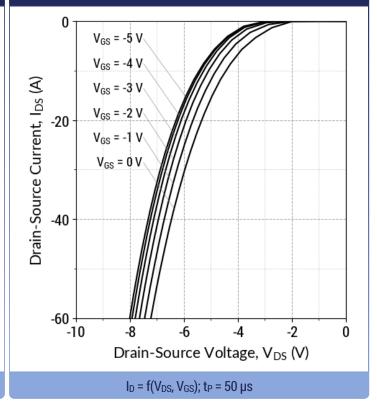


Fig 20: Typical Body Diode Characteristics ($T_j = -55$ °C)



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Fig 21: Typical Third Quadrant Characteristics ($T_j = 25$ °C)

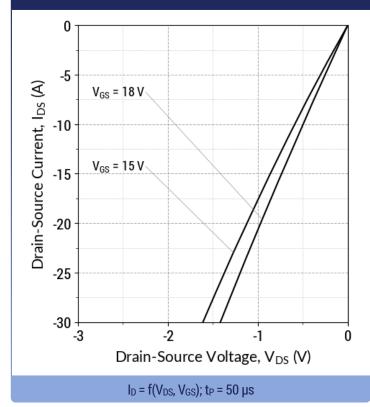
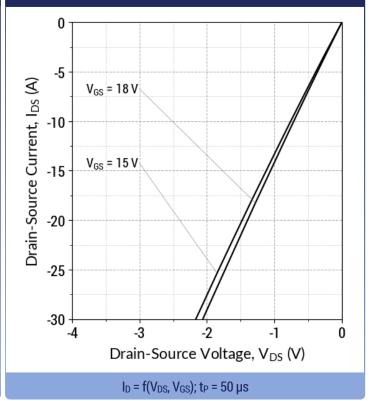


Fig 22: Typical Third Quadrant Characteristics (T_j = 175°C)



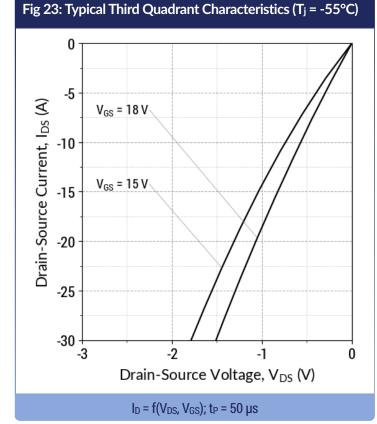
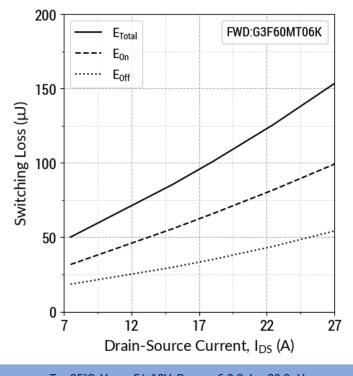


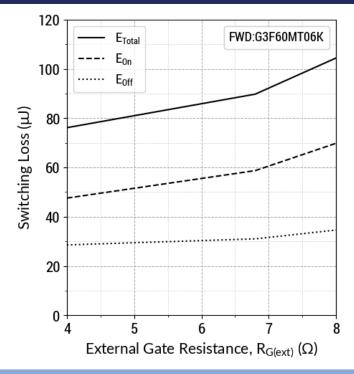
Fig 24: Inductive Switching Energy v/s Drain Current $(V_{DD} = 400V)$



 $T_j = 25$ °C; $V_{GS} = -5/+18V$; $R_{G(ext)} = 6.8 \Omega$; $L = 80.0 \mu H$

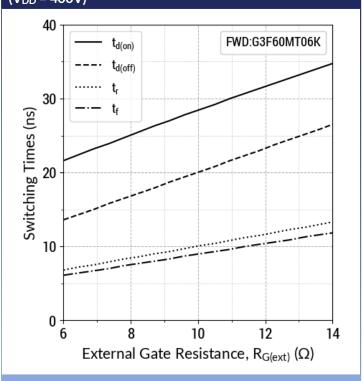
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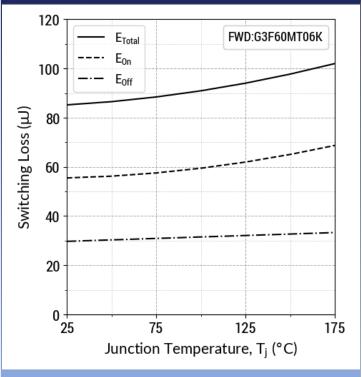
 $T_i = 25$ °C; $V_{GS} = -5/+18V$; $I_{DS} = 15$ A; $L = 80.0 \mu H$

Fig 26: Switching Time v/s $R_{G(ext)}$ ($V_{DD} = 400V$)



 $T_i = 25$ °C; $V_{GS} = -5/+18V$; $I_{DS} = 15$ A; $L = 80.0 \mu H$

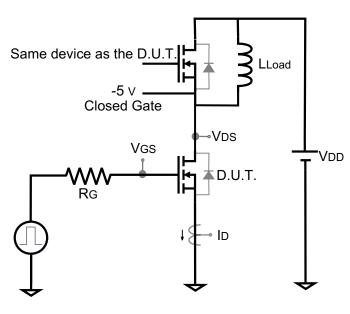
Fig 27: Inductive Switching Energy v/s Temperature $(V_{DD} = 400V)$



 $T_i = 25^{\circ}C$; $V_{GS} = -5/+18V$; $R_{G(ext)} = 6.8 \Omega$; $I_{DS} = 15 A$; $L = 80.0 \mu H$

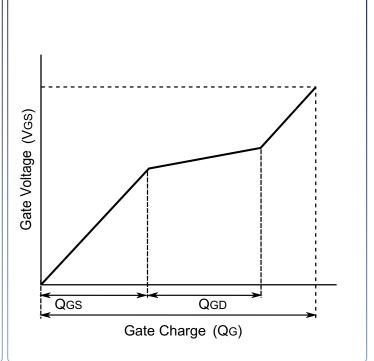
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Dynamic Test Circuit

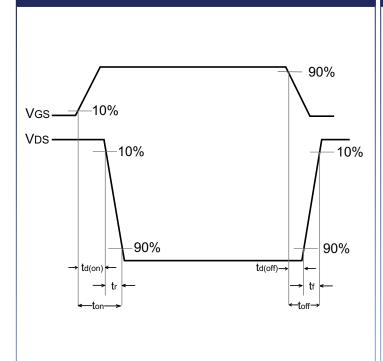


Note: Gate Charge, Switching Time and Energy Circuit

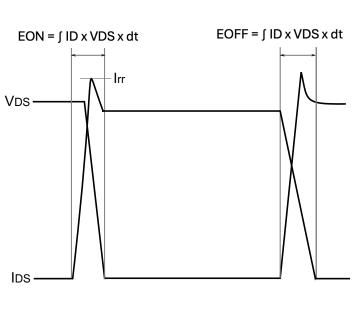
Gate Charge Waveform



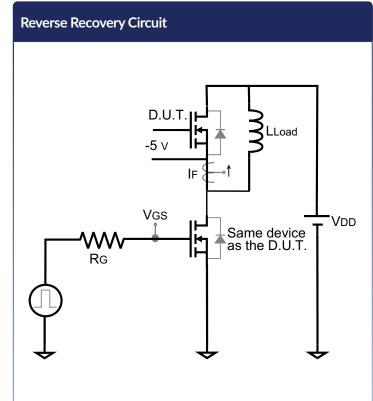
Switching Time Waveform

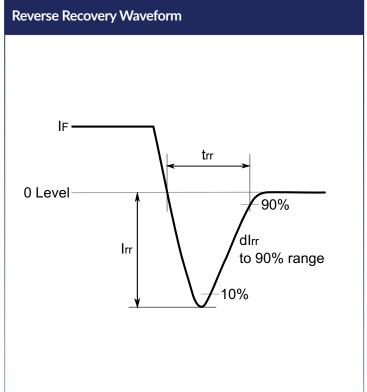


Switching Energy Waveform



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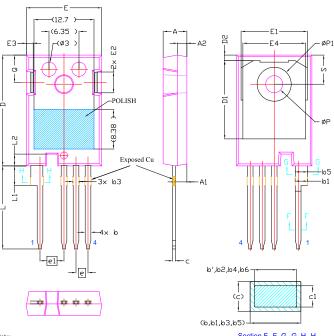
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Package Dimensions

TO-247-4 Package Outline



Section F--F, G-G, H--H

Note:

J. All Dimensions Are In mm.
Slot Required, Notch May Be Rounded
Dimension D & E Do Not Indude Mold Flash. Mold Flash Shall Not Exceed O.12mm Pre Side. These Dimensions Are Measured At The Outermost Extreme Of The Plastic Body.
Themal Pad Contour Optional Within Dimension D1 & E1.
Lead Finish Uncontrolled In L1.
DP To Have A Draft Angle Of 1.5° (REF.) To The Top Of The Part With Hole Diameter Of 3.91mm (REF.).

SYMBOL MIN. NOM. MAX. A 4.83 5.02 5.21 A1 2.29 2.41 2.54 A2 1.91 2.00 2.16 b' 1.07 1.20 1.28 b 1.07 1.20 1.33 b1 2.39 2.67 2.94 b2 2.39 2.67 2.94 b3 1.07 1.30 1.50 b4 1.07 1.30 1.50 b5 2.39 2.53 2.69 b6 2.39 2.53 2.64 c 0.55 0.60 0.68 c1 0.55 0.60 0.65 D 23.30 23.45 23.60 D1 16.25 16.55 17.65 D2 0.95 1.19 1.25 E 15.75 15.94 16.13 E1 13.10 14.02 14.15 E2 <
A1 2,29 2,41 2,54 A2 1,91 2,00 2,16 b' 1,07 1,20 1,28 b 1,07 1,20 1,33 b1 2,39 2,67 2,94 b2 2,39 2,67 2,84 b3 1,07 1,30 1,50 b4 1,07 1,30 1,50 b5 2,39 2,53 2,69 b6 2,39 2,53 2,64 c 0,55 0,60 0,68 c1 0,55 0,60 0,65 D 23,30 23,45 23,60 D1 16,25 16,55 17,65 D2 0,95 1,19 1,25 E 15,75 15,94 16,13 E1 13,10 14,02 14,15 E2 3,68 4,40 5,10 E3 1,00 1,45 1,90 E4
A2 1,91 2,00 2,16 b 1,07 1,20 1,28 b 1,07 1,20 1,33 b1 2,39 2,67 2,94 b2 2,39 2,67 2,84 b3 1,07 1,30 1,50 b4 1,07 1,30 1,50 b5 2,39 2,53 2,69 b6 2,39 2,53 2,64 c 0,55 0,60 0,68 c1 0,55 0,60 0,68 D 23,30 23,45 23,60 D1 16,25 16,55 17,65 D2 0,95 1,19 1,25 E 15,75 15,94 16,13 E1 13,10 14,02 14,15 E2 3,68 4,40 5,10 E3 1,00 1,45 1,90 E4 12,38 13,26 13,43
b' 1.07 1.20 1.28 b 1.07 1.20 1.33 b1 2.39 2.67 2.94 b2 2.39 2.67 2.84 b3 1.07 1.30 1.50 b4 1.07 1.30 1.50 b5 2.39 2.53 2.64 c 0.55 0.60 0.68 c1 0.55 0.60 0.68 c1 0.55 16.55 17.65 D2 23.30 23.45 23.60 D1 16.25 16.55 17.65 D2 0.95 1.19 1.25 E 15.75 15.94 16.13 E1 13.10 14.02 14.15 E2 3.68 4.40 5.10 E3 1.00 1.45 1.90 E4 12.38 13.26 13.43
b 1.07 1.20 1.33 b1 2.39 2.67 2.94 b2 2.39 2.67 2.84 b3 1.07 1.30 1.60 b4 1.07 1.30 1.50 b5 2.39 2.53 2.69 b6 2.39 2.53 2.64 c 0.55 0.60 0.68 c1 0.55 0.60 0.68 c1 0.55 0.60 0.65 D 23.30 23.45 23.60 D1 16.25 16.55 17.65 D2 0.95 1.19 1.25 E 15.75 15.94 16.13 E1 13.10 14.02 14.15 E2 3.68 4.40 5.10 E3 1.00 1.45 1.90 E4 12.38 13.26 13.43
b1 2.39 2.67 2.94 b2 2.39 2.67 2.84 b3 1.07 1.30 1.60 b4 1.07 1.30 1.50 b5 2.39 2.53 2.69 b6 2.39 2.53 2.64 c 0.55 0.60 0.68 c1 0.55 0.60 0.65 D 23.30 23.45 23.60 D1 16.25 16.55 17.65 D2 0.95 1.19 1.25 E 15.75 15.94 16.13 E1 13.10 14.02 14.15 E2 3.68 4.40 5.10 E3 1.00 1.45 1.90 E4 12.38 13.26 13.43
b2 2.39 2.67 2.84 b3 1.07 1.30 1.60 b4 1.07 1.30 1.50 b5 2.39 2.53 2.69 b6 2.39 2.53 2.64 c 0.55 0.60 0.68 c1 0.55 0.60 0.65 D 23.30 23.45 23.60 D1 16.25 16.55 17.65 D2 0.95 1.19 1.25 E 15.75 15.94 16.13 E1 13.10 14.02 14.15 E2 3.68 4.40 5.10 E3 1.00 1.45 1.90 E4 12.38 13.26 13.43
b3 1.07 1.30 1.60 b4 1.07 1.30 1.50 b5 2.39 2.53 2.69 b6 2.39 2.53 2.64 c 0.55 0.60 0.68 c1 0.55 0.60 0.65 D 23.30 23.45 23.60 D1 16.25 16.55 17.65 D2 0.95 1.19 1.25 E 15.75 15.94 16.13 E1 13.10 14.02 14.15 E2 3.68 4.40 5.10 E3 1.00 1.45 1.90 E4 12.38 13.26 13.43
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E3 1.00 1.45 1.90 E4 12.38 13.26 13.43
E4 12.38 13.26 13.43
e 2.54 BSC
e1 5.08 BSC
L 17.31 17.57 17.82
L1 3.97 4.19 4.37
L2 2.35 2.50 2.65
ØP 3.51 3.61 3.65
ØP1 7.19 REF.
Q 5.49 5.79 6.00
S 6.04 6.17 6.30

NOTE

- 1. CONTROLLED DIMENSION IS MILLIMETER.
- 2. DIMENSIONS DO NOT INCLUDE END FLASH, MOLD FLASH, MATERIAL PROTRUSIONS.
- 3. THE SOURCE AND KELVIN-SOURCE PINS ARE NOT INTERCHANGABLE. THEIR EXCHANGE MIGHT LEAD TO MALFUNCTION.

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Revision History

Rev 24/Aug: Initial Release (Rev 1.0)

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